

Description

The AOD454A uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



TO-252-2L

General Features

 $V_{DS} = 40V I_{D} = 25 A$

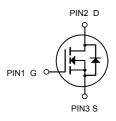
 $R_{DS(ON)}$ < 25m Ω @ V_{GS} =10V

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

| Product ID | Pack | Brand | Qty(PCS) |
|------------|----------|------------|----------|
| AOD454A | TO252-2L | HXY MOSFET | 2500 |

Absolute Maximum Ratings (T_C=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Units |
|---------------------------------------|--|------------|-------|
| VDS | Drain-Source Voltage | 40 | V |
| Vgs | Gate-Source Voltage | ±20 | V |
| I _D @T _C =25°C | Continuous Drain Current, V _{GS} @ 10V ¹ | 25 | А |
| I _D @T _C =100°C | Continuous Drain Current, V _{GS} @ 10V ¹ | 17 | А |
| Ірм | Pulsed Drain Current ² | 100 | А |
| EAS | Single Pulse Avalanche Energy ³ | 23 | mJ |
| P _D @T _C =25°C | Total Power Dissipation ⁴ | 26 | W |
| Тѕтс | Storage Temperature Range | -50 to 150 | °C |
| TJ | Operating Junction Temperature Range | -50 to 150 | °C |
| Reja | Thermal Resistance Junction-ambient | 62 | °C/W |
| Rejc | Thermal Resistance Junction-Case | 4.8 | °C/W |



Electrical Characteristics (T_J = 25°C, unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Тур | Max | Units |
|---------------------|---------------------------------|---|-----|-----|------|-------|
| BV _{DSS} | Drain-Sourtce Breakdown Voltage | V _{GS} =0V,I _D =250μA | 40 | | | V |
| | Zero Gate Voltage Drain Current | V _{GS} =0V, V _{DS} =40V | | | 1 | μA |
| I _{DSS} | | V _{GS} =0V, V _{DS} =32V | | | 10 | μA |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} =±20V, V _{DS} =0A | | | ±100 | nA |
| V _{GS(th)} | Gate-Source Threshold Voltage | $V_{GS}=V_{DS}, I_D=250\mu A$ | 1.2 | 1.6 | 2.5 | V |
| _ | | V _{GS} =10V,I _D =12A | | 18 | 25 | mΩ |
| R _{DS(ON)} | Drain-Source On Resistance | V _{GS} =4.5V,I _D =10A | | 25 | 35 | mΩ |
| C _{iss} | Input Capacitance | V_{DS} =25V, V_{GS} =0V, f=1MHz | | 825 | | |
| C _{oss} | Output Capacitance | | | 70 | | pF |
| C _{rss} | Reverse Transfer Capacitance | | | 39 | | |
| t _{d(on)} | Turn-On Delay Time | | | 2.2 | | ns |
| t _r | Rise Time | V_{DD} =20V, I_D =1A, | | 7.6 | | ns |
| $t_{	ext{d(off)}}$ | Turn-Off Delay Time | R_{ENG} =25 Ω , V_{GS} =4.5 V | | 17 | | ns |
| t _f | Fall Time | | | 5 | | ns |
| Q _{gs} | Total Gate Charge | V _{GS} =10V, V _{DS} =20V, I _D =5A | | 1.3 | | nC |
| Q_gd | Gate-Source Charge | | | 1.7 | | nC |
| Q_g | Gate-Drain "Miller" Charge | | | 13 | | nC |
| V _{SD} | Diode Forward Voltage | V _{GS} =0V, I _S =1A | | | 1 | V |
| I _S | Continuous Drain Curren | VD=VG=0V | | | 25 | А |
| Ism | Pulsed Drain Current | | | | 95 | А |

Notes:

- 1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
- 2. EAS condition : TJ=25 $^{\circ}$ C,VDD=30V,VG=10V,L=0.5mH
- 3. Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%



Typical Characteristics

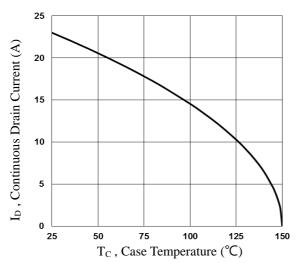


Fig.1 Continuous Drain Current vs. TC

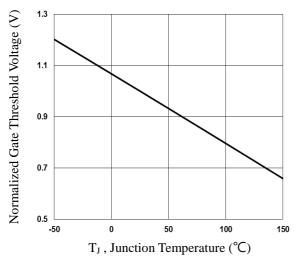


Fig.3 Normalized V_{th} vs. T_J

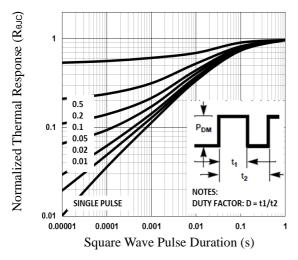


Fig.5 Normalized Transient Impedance

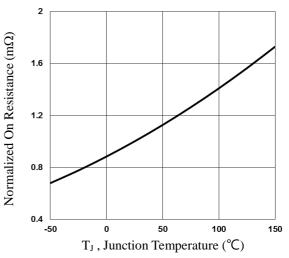


Fig.2 Normalized RDSON vs. TJ

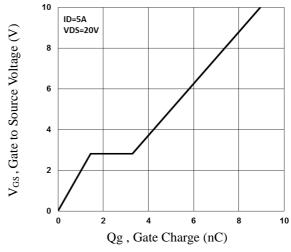


Fig.4 Gate Charge Characteristics

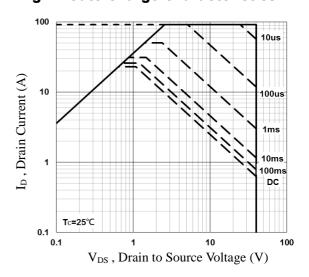
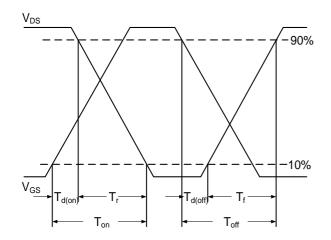


Fig.6 Maximum Safe Operation Area



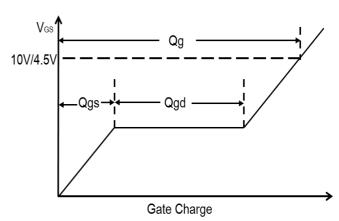


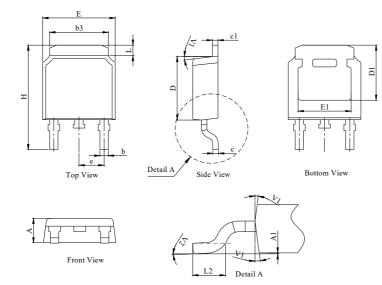
Fig.7 Switching Time Waveform

Fig.8 Gate Charge Waveform



TO252-2L Package Information

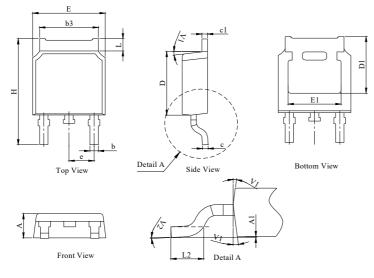
Package Outline Type-A



UNIT: mm

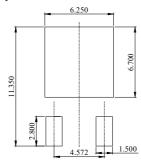
| | MILLIMETER | | | |
|------|------------|-------|-------|--|
| DIM. | MIN. | NOM. | MAX. | |
| A | 2.18 | 2.30 | 2.39 | |
| A1 | 0 | | 0.13 | |
| b | 0.64 | 0.76 | 0.89 | |
| c | 0.40 | 0.50 | 0.61 | |
| c1 | 0.46 | 0.50 | 0.58 | |
| D | 5.97 | 6.10 | 6.23 | |
| D1 | 5.05 | | | |
| E | 6.35 | 6.60 | 6.73 | |
| E1 | 4.32 | | | |
| b3 | 5.21 | 5.38 | 5.55 | |
| e | 2.29 BSC | | | |
| Н | 9.40 | 10.00 | 10.40 | |
| L | 0.89 | | 1.27 | |
| L2 | 1.40 | | 1.78 | |
| V1 | 7° REF | | | |
| V2 | 0° | | 6° | |

Package Outline Type-B



| DIM. | MILLIMETER | | | |
|------|------------|-------|-------|--|
| | MIN. | NOM. | MAX. | |
| A | 2.10 | 2.30 | 2.40 | |
| A1 | 0 | | 0.13 | |
| b | 0.66 | 0.76 | 0.86 | |
| b3 | 5.21 | 5.38 | 5.55 | |
| с | 0.40 | 0.50 | 0.60 | |
| c1 | 0.44 | 0.50 | 0.58 | |
| D | 5.90 | 6.10 | 6.30 | |
| D1 | 5.30REF | | | |
| E | 6.40 | 6.60 | 6.80 | |
| E1 | 4.63 | - | - | |
| e | 2.29 BSC | | | |
| Н | 9.50 | 10.00 | 10.70 | |
| L | 1.09 | | 1.21 | |
| L2 | 1.35 | | 1.65 | |
| V1 | 7° REF | | | |
| V2 | 0° | | 6° | |
| | | | | |

Recommended Soldering Footprint





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